Datasheet.Direc

Silicon NPN transistors, general purpose (chip)
Transistors NPN silicium, usage général (pastille)

Type *Type*	V_{CBO} (V)	V_{CEO} (V) V_{CER} *	I_C (mA)	h_{21E} min - max	/	V_{CE} (V)	I_C (mA)
J.2N 1613	75	50*	1000	40 - 120*		10	150
J.2N 1711	75	50*	1000	100 - 300*		10	150
J.2N 1893	120	80	1000	40 - 120*		10	150
J.2N 2221	60	30	800	40 - 120*		10	150
J.2N 2221 A	75	40	800	40 - 120*		10	150
J.2N 2222	60	30	800	100 - 300*		10	150
J.2N 2222 A	75	40	800	100 - 300*		10	150
J.BSX 51	25	25	200	75 - 225		4,5	2
J.BSX 51 A	50	50	200	75 - 220		4,5	2
J.BSX 52	25	25	200	180 - 540		4,5	2
J.BSX 52 A	50	50	200	180 - 540		4,5	2

Silicon PNP transistors, general purpose (chip)
Transistors PNP silicium, usage général (pastille)

Type *Type*	V_{CBO} (V)	V_{CEO} (V)	I_C (mA)	h_{21E} min - max	/	V_{CE} (V)	I_C (mA)
J.2N 2906	–60	–40	–600	40 - 120*		–10	–150
J.2N 2906 A	–60	–60	–600	40 - 120*		–10	–150
J.2N 2907	–60	–40	–600	100 - 300*		–10	–150
J.2N 2907 A	–60	–60	–600	100 - 300*		–10	–150
J.BSW 21	–25	–25	–200	75 - 225		–4,5	–2
J.BSW 21 A	–50	–50	–200	75 - 225		–4,5	–2
J.BSW 22	–25	–25	–200	180 - 540		–4,5	–2
J.BSW 22 A	–50	–50	–200	180 - 540		–4,5	–2

* Pulsed
Impulsions